

FQP17P10

Data Sheet

Trans MOSFET P-CH 100V 16.5A 3-Pin(3+Tab) TO-220AB Tube

Manufacturers ON Semiconductor, LLC

Package/Case TO-220

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for FQP17P10 or Email to us: sales@ovaga.com We will contact you in 12 hours.



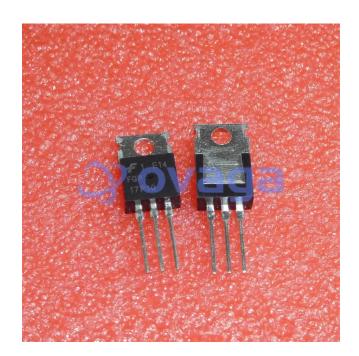
General Description

This P-Channel enhancement mode power MOSFET is produced using a proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features Application

175°C maximum junction temperature rating ONSEMI





Related Products



FQT7N10LTF

ON Semiconductor, LLC SOT-223



FQD19N10LTM

ON Semiconductor, LLC TO-252



FQA140N10

ON Semiconductor, LLC TO-3P



FQB5N90TM

ON Semiconductor, LLC TO-263



FQPF13N50CF

ON Semiconductor, LLC TO-220F



FQD12N20LTM

ON Semiconductor, LLC TO-252



FQPF70N10

ON Semiconductor, LLC TO-220F



FQB27P06TM

ON Semiconductor, LLC

TO-263